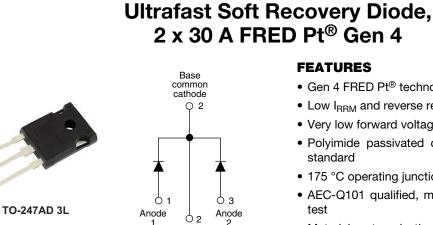
# VS-C4PU6006LHN3

**Vishay Semiconductors** 

# www.vishay.com

2 3



Common cathode

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 30 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.19 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Common cathode				

### **FEATURES**

- Gen 4 FRED Pt<sup>®</sup> technology
- Low I<sub>BBM</sub> and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 gualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	٨			
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 8.3 ms, half sine wave	240	A			
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Free of all the second s		I <sub>F</sub> = 30 A	-	1.36	1.6		
		I <sub>F</sub> = 60 A	-	1.6	-	V	
	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-		
Forward voltage		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-		
		$V_{R} = V_{R}$ rated	-	-	50		
Reverse leakage current	I <sub>R</sub>	$T_J = 125 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	18.3	-	pF	



RoHS COMPLIANT HALOGEN FREE

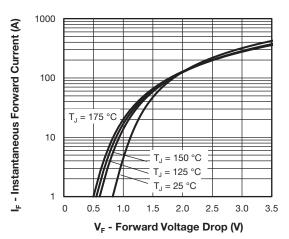
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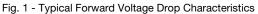


# **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Bayaraa raaayany tima	+	T <sub>J</sub> = 25 °C	L 20 A	-	65	-	ns	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	90	-		
Peak recovery current		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs	-	18	-	А	
Feat recovery current	IRRM	T <sub>J</sub> = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	32	-		
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	850	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1850	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1	°C/W	
Thermal resistance, case to heat sink	R <sub>thCS</sub>		-	0.4	-		
Weight			-	6.0	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6.0	_	12	kgf · cm	
			(5)	_	(10)	(lbf · in)	
Marking device		Case style TO-247AD 3L	C4PU3006LH				





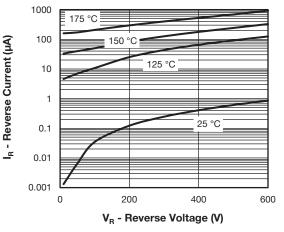


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

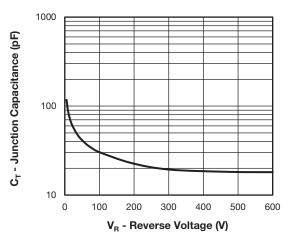
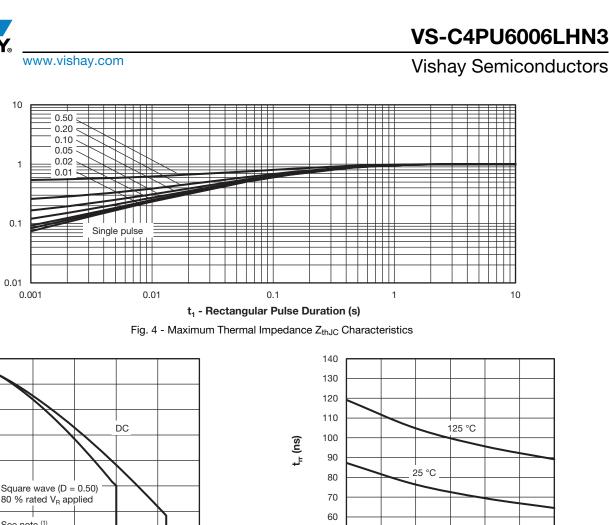


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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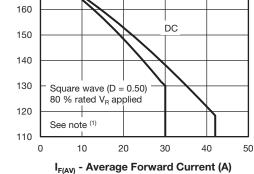


50

400

500

600

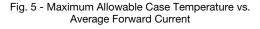


Z<sub>thJC</sub> - Thermal Impedance Junction to Case (°C/W)

180

170

Allowable Case Temperature (°C)



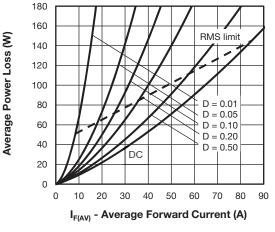


Fig. 6 - Forward Power Loss Characteristics

### Note

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<sup>(1)</sup> Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see Fig.5)  $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_R$  = rated  $V_R$ 

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# Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

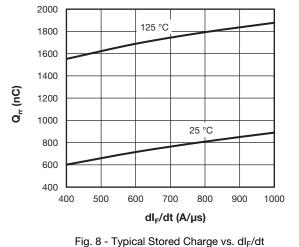
700

dl<sub>r</sub>/dt (A/µs)

800

900

1000



# VS-C4PU6006LHN3

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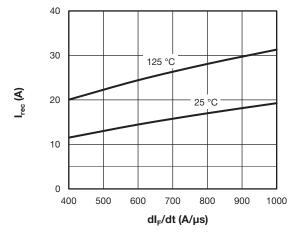


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

## **ORDERING INFORMATION TABLE**

Device code	VS-	С	4	Р	U	60	06	L	н	N3
	1	2	3	4	5	6	7	8	9	10
	1 - 2 -	Circ	uit conf	niconduc	ו:	oduct				
	3 -	FRE	ED Pt G	on diode en 4 <sup>°</sup> packag						
	5 -	Pro	cess typ							
	6 - 7 -			ng (60 = ng (06 =						
	8 - 9 -		•	= long l 101 qua						
	10 -			ntal digit: en-free,		ompliar	nt, and t	otally le	ad (Pb)	-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-C4PU6006LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		

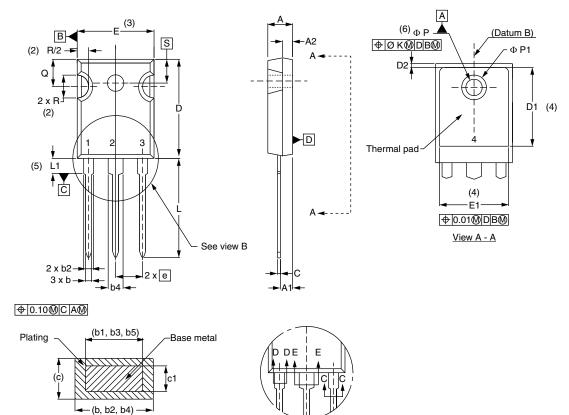
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**Vishay Semiconductors** 

TO-247AD 3L

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	0.254		)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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